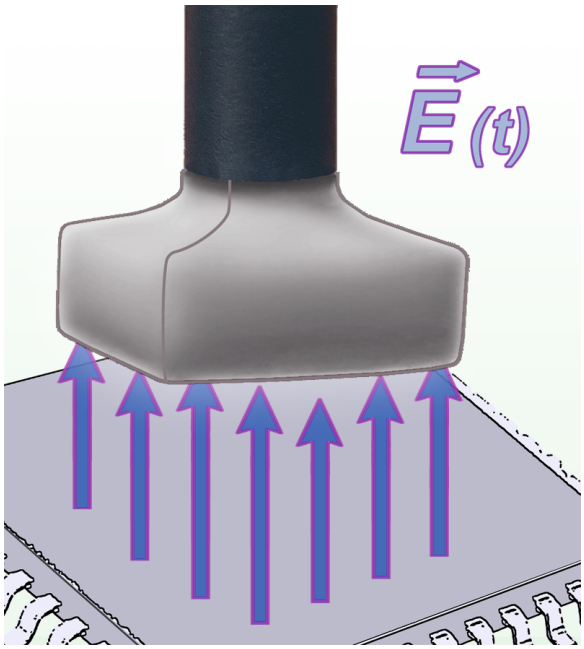
XF-E 09s

E-Field Probe 30 MHz up to 6 GHz



Short description

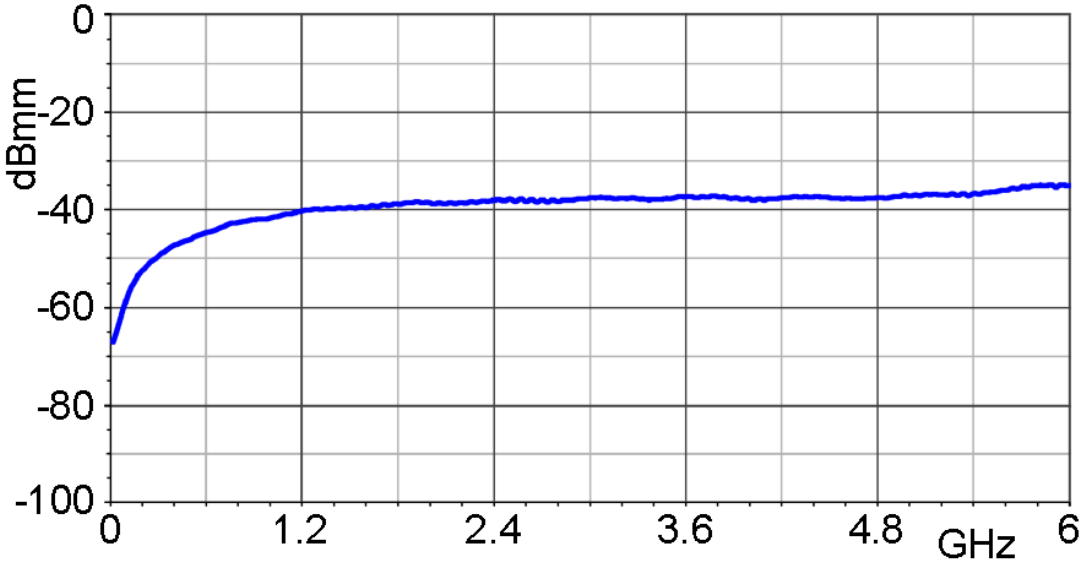
The electrode on the probe head of the XF-E 09s near-field probe detects electrical fields which, for example are decoupled above the IC's surface. The probe's resolution allows for measurements at a distance of 0.5 mm upto 10 mm above an assembly.

The XF-E 09s is a passive near-field probe. In principle it has the same structure as the XF-E 04s probe. To measure, the E-field probe is positioned above or onto components and printed circuit boards. It has a current attenuating sheath and, therefore, its upper half is electrically shielded. It can be connected to a spectrum analyzer or an oscilloscope with a 50 Ω input. The E-field probe has an internal terminating resistance.

Technical parameters

Frequency range	30 MHz ... 6 GHz
Probe head dimensions	≈ (10 x 10) mm
Connector - output	SMA, female, jack

Frequency response [dBµV] / [dBµV/mm]

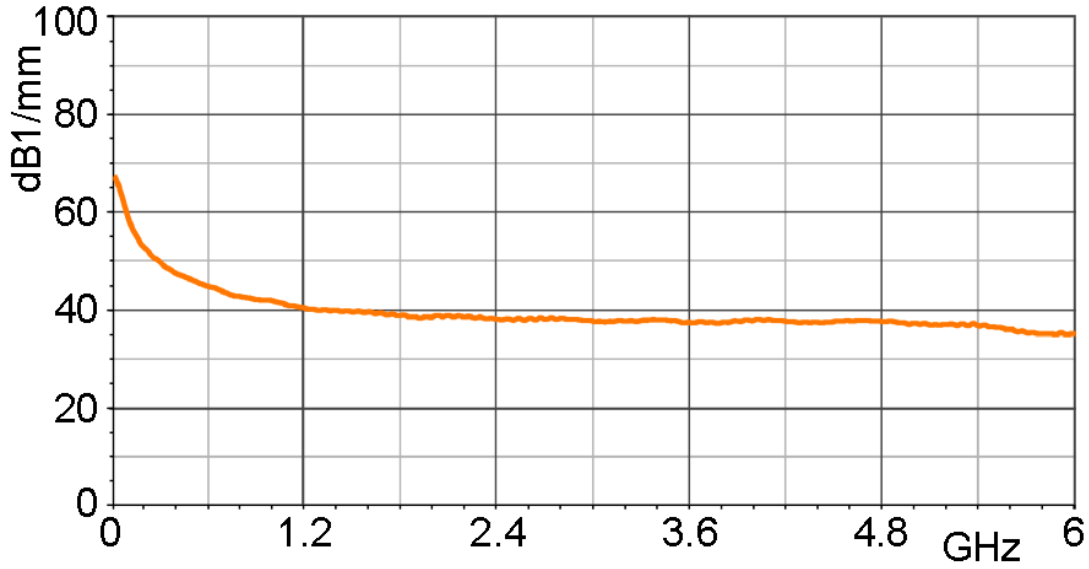


Sales Partner:

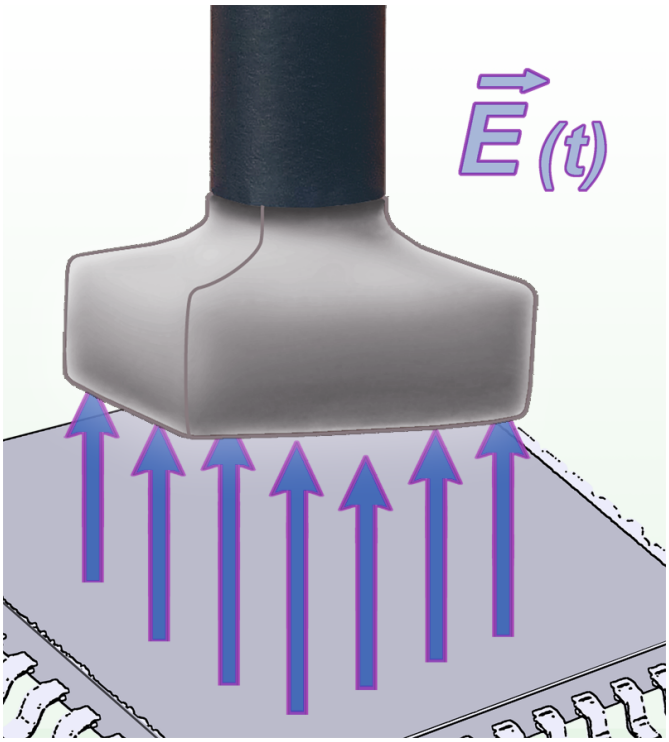
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E- field correction curve [dBµV/mm] / [dBµV]



Measuring principles



XF-E 09s

E-Field Probe 30 MHz up to 6 GHz

Probe head

